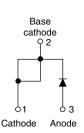


## VS-MBR16...PbF Series, VS-MBR16...-N3 Series

**Vishay Semiconductors** 





TO-220AC	
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PRODUCT SUMMARY							
Package	TO-220AC						
I <sub>F(AV)</sub>	16 A						
V <sub>R</sub>	35 V, 45 V						
V <sub>F</sub> at I <sub>F</sub>	0.57 V						
I <sub>RM</sub> max.	40 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
Diode variation	Single die						
E <sub>AS</sub>	24 mJ						

# Schottky Rectifier, 16 A

### FEATURES

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

#### DESCRIPTION

The VS-MBR16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	16	A						
V <sub>RRM</sub>		35/45	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1800	A						
V <sub>F</sub>	16 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V						
TJ	Range	- 65 to 150	°C						

VOLTAGE RATINGS										
PARAMETER	SYMBOL	VS-MBR1635PbF	VS-MBR1635-N3	VS-MBR1645PbF	VS-MBR1645-N3	UNITS				
Maximum DC reverse voltage	V <sub>R</sub>	35	35	45	45	v				
Maximum working peak reverse voltage	V <sub>RWM</sub>	55		45	40					

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONI	DITIONS	VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	$T_{C}$ = 134 °C, rated $V_{R}$	$T_{C} = 134 \text{ °C}, \text{ rated } V_{R}$							
Non-repetitive peak surge current	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1800	А					
		Surge applied at rated load condition half wave single phase, 60 Hz		150						
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25 \text{ °C}, I_{AS} = 3.6 \text{ A}, L = 3.7$	24	mJ						
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to ze Frequency limited by T <sub>J</sub> maxir	3.6	А						

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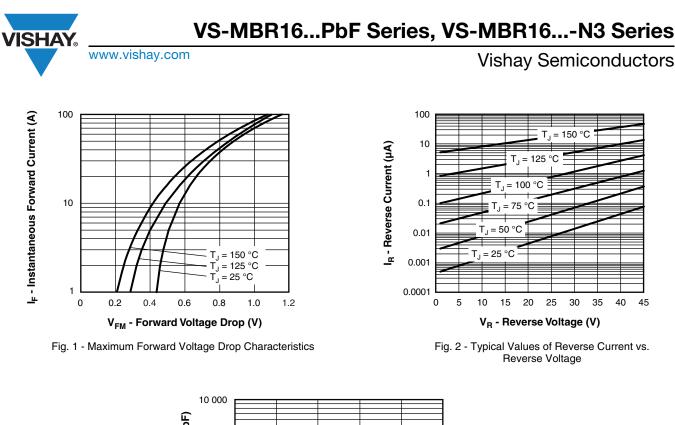
## Vishay Semiconductors

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS						
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	16 A	T <sub>J</sub> = 25 °C	0.63	V				
Maximum forward voltage drop	VFM (')	10 A	T <sub>J</sub> = 125 °C	0.57	v				
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.2	mA				
Maximum instantaneous reverse current	IRM \''	T <sub>J</sub> = 125 °C	haled DC vollage	40					
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal rang	ge 100 kHz to 1 MHz) 25 °C	1400	pF				
Typical series inductance	L <sub>S</sub>	Measured from top of termi	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs				

Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Maximum junction temperature range	TJ		- 65 to 150	°C						
Maximum storage temperature range	T <sub>Stg</sub>		- 65 to 175	U						
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	1.50	°C/W						
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	0/10						
Approximate weight			2	g						
			0.07	oz.						
Mounting torque			6 (5)	kgf ⋅ cm						
Mounting torque maximum			12 (10)	(lbf ⋅ in)						
Marking davies			MBR1635							
Marking device		Case style TO-220AC (JEDEC)		1645						



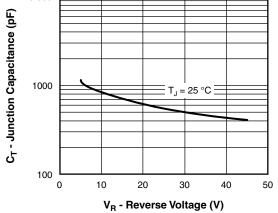
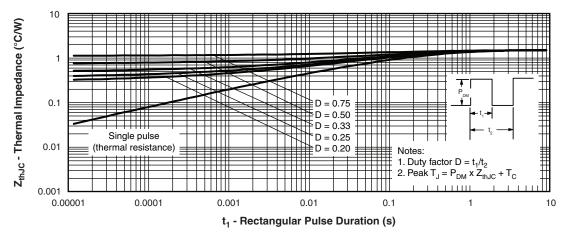
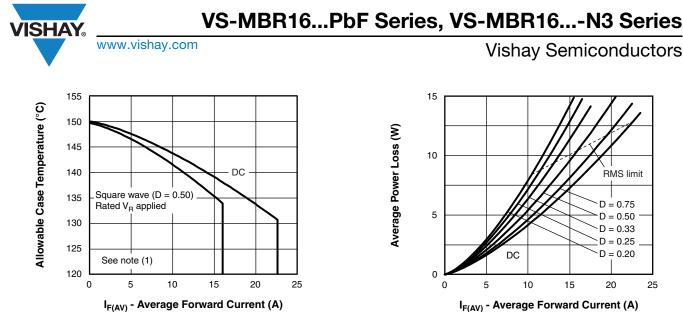


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





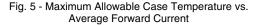
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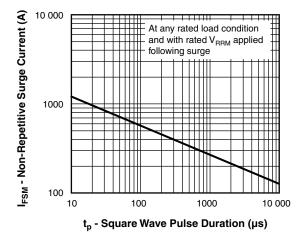


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

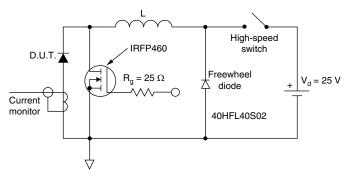


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $Pd_{REV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = Rated  $V_R$  applied

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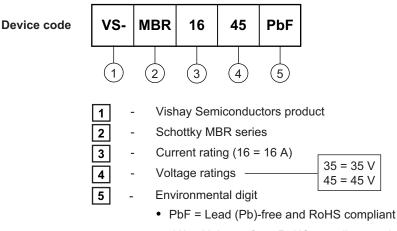
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Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6);



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### **ORDERING INFORMATION TABLE**



• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-MBR1635PbF	50	1000	Antistatic plastic tube							
VS-MBR1635-N3	50	1000	Antistatic plastic tube							
VS-MBR1645PbF	50	1000	Antistatic plastic tube							
VS-MBR1645-N3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95221							
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224					
Part marking information	TO-220AC -N3	www.vishay.com/doc?95068					



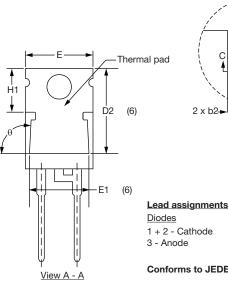
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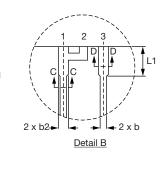
**TO-220AC** 

plane

#### **DIMENSIONS** in millimeters and inches









**Diodes** 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL		IETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183		E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055		E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115		е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040		e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4	H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068		L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4	L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024		L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4	L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3	ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355		Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6	θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6						

Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Dimension b1, b3 and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimension: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1
- <sup>(7)</sup> Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- <sup>(8)</sup> Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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